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HMC942* Product Page Quick Links

Last Content Update: 08/30/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC942LP4E Evaluation Board

Documentation

Data Sheet

- HMC942 Data Sheet

Reference Materials

Quality Documentation

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Semiconductor Qualification Test Report: PHEMT-F (QTR: 2013-00269)

Design Resources

- HMC942 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC942 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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MICROWAVE CORPORATION v02.1210



HMC942LP4E

SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 25 - 31 GHz OUTPUT

Typical Applications

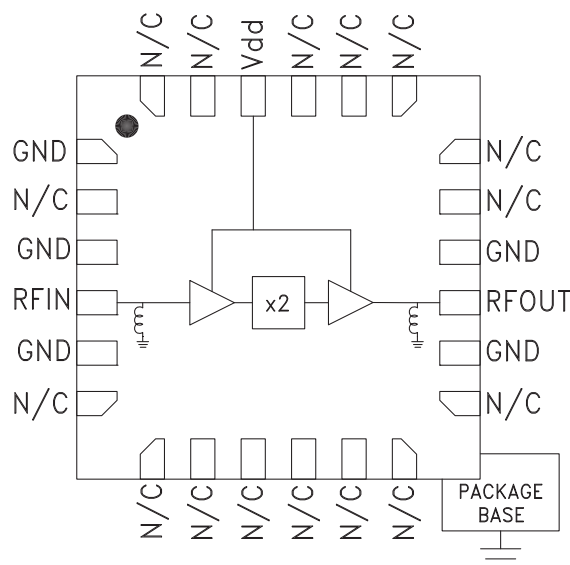
The HMC942LP4E is ideal for:

- Clock Generation Applications:
SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space
- Sensors

Features

- High Output Power: +21 dBm
- Low Input Power Drive: 0 to +6 dBm
- Fo Isolation: >45 dBc
- Single Supply: +4.5V @ 214 mA
- 24 Lead 4x4 mm SMT Package: 16 mm²

Functional Diagram



General Description

The HMC942LP4E is a x2 active broadband frequency multiplier utilizing GaAs pHEMT technology in a leadless RoHS compliant SMT package. When driven by a +4 dBm signal, the multiplier provides +17 dBm typical output power from 13 to 24.6 GHz. The Fo and 3Fo isolations are >20 dBc at 19 GHz. The HMC942LP4E is ideal for use in LO multiplier chains for Pt-to-Pt & VSAT Radios yielding reduced parts count vs. traditional approaches.

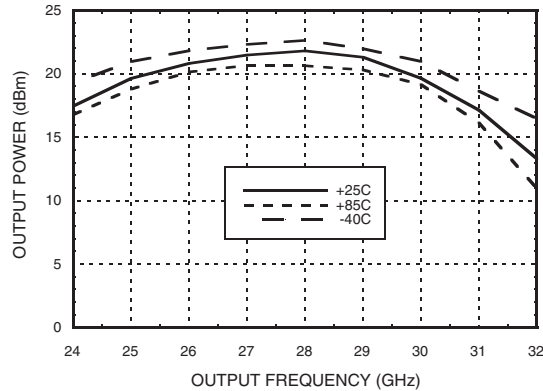
Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = +4.5\text{V}$, +4 dBm Drive Level

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, Input		12.5 - 15.0		15.0 - 15.5			GHz
Frequency Range, Output		25 - 30		30 - 31			GHz
Output Power	17	21		14	18		dBm
Fo Isolation (with respect to output level)		55			55		dBc
Input Return Loss	4	12		4	9		dB
Output Return Loss	6	12		5	10		dB
Supply Current (Idd1 & Idd2)		214	240		214	240	mA

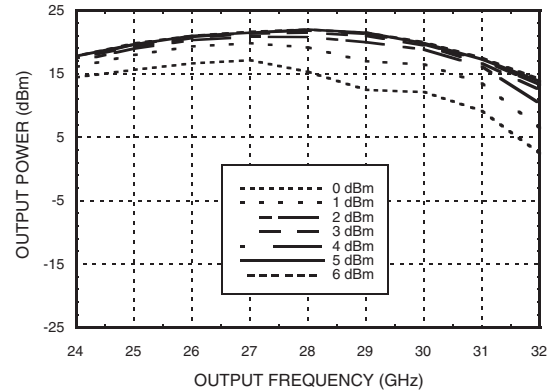


**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 25 - 31 GHz OUTPUT**

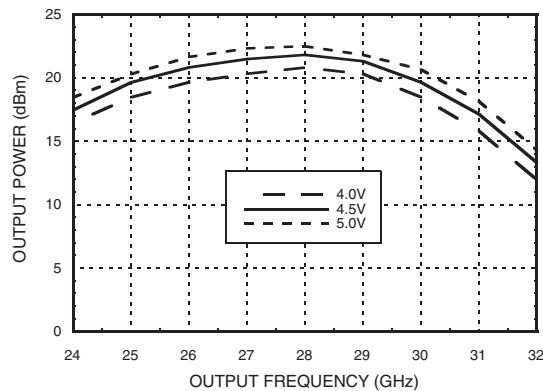
**Output Power vs.
Temperature @ +4 dBm Drive Level**



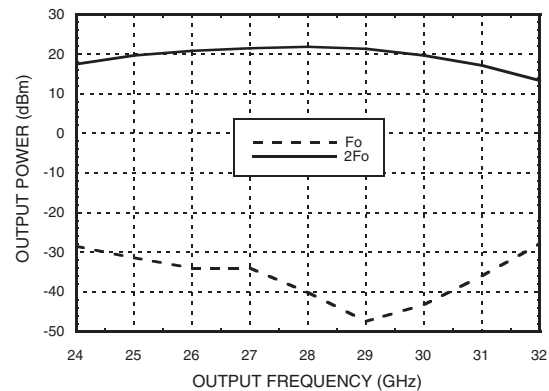
Output Power vs. Drive Level



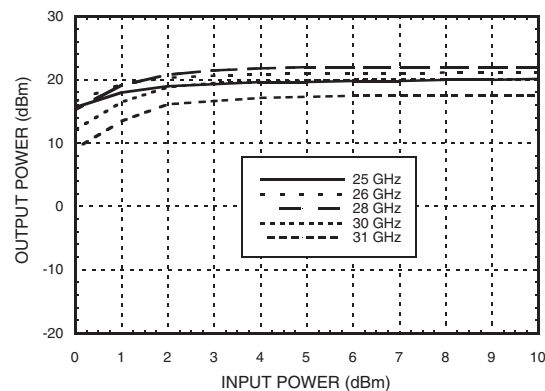
**Output Power vs.
Supply Voltage @ +4 dBm Drive Level**



Isolation @ +4 dBm Drive Level



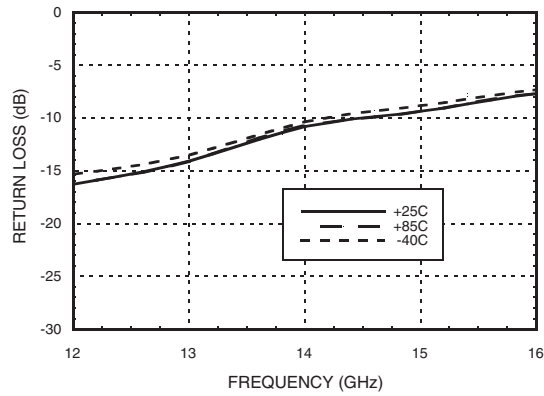
Output Power vs. Input Power



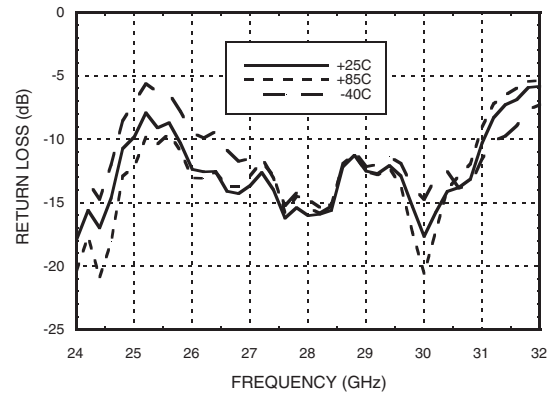


**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 25 - 31 GHz OUTPUT**

Input Return Loss vs. Temperature



Output Return Loss vs. Temperature





v02 1210



**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 25 - 31 GHz OUTPUT**

Typical Supply Current vs. Vdd

RF Input (Vdd = +5V)	+10 dBm
Supply Voltage (Vdd1, Vdd2)	+5.5 Vdc
Channel Temperature	175 °C
Continuous P _{dis} (T= 85 °C) (derate 16.4 mW/°C above 85 °C)	1.48 W
Thermal Resistance (channel to ground paddle)	60 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1B

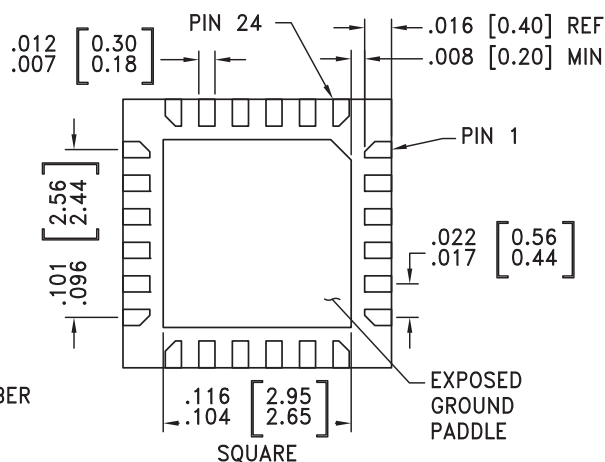
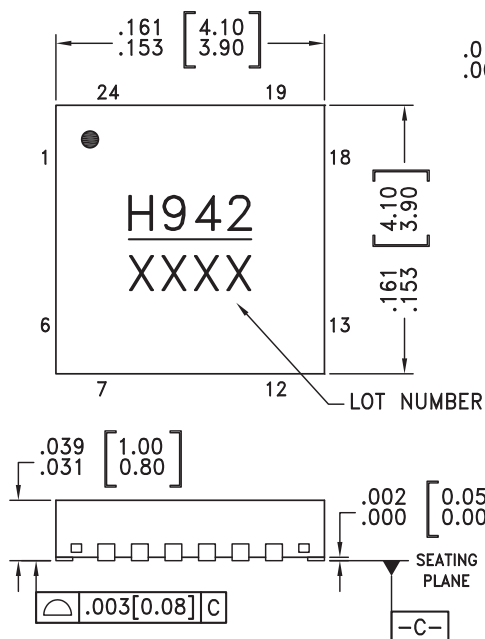
Vdd (Vdc)	Idd (mA)
4.0	211
4.5	214
5.0	217

Multiplier will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

BOTTOM VIEW



1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC942LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H942</u> <u>XXXX</u>

[2] Max peak reflow temperature of 260 °C

Application Support: Phone: 978-250-3343 or apps@hittite.com



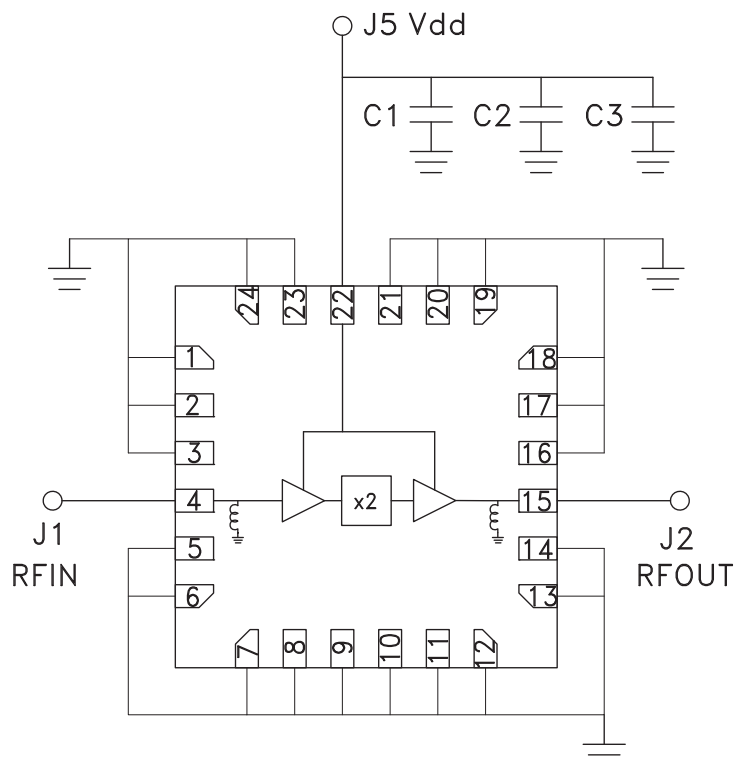
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**HMC942LP4E****SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 25 - 31 GHz OUTPUT****Pin Description**

Pin Number	Function	Description	Interface Schematic
1, 3, 5, 6, 7, 12, 13, 14, 16, 18, 19, 24	GND	Package bottom must also be connected to RF/DC ground.	
4	RFIN	This pin is DC coupled and matched to 50 Ohms.	
2, 8, 9, 10, 11, 17, 20, 21, 23	N/C	These pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground.	
15	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
22	Vdd	Supply voltage 4.5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 µF are recommended.	

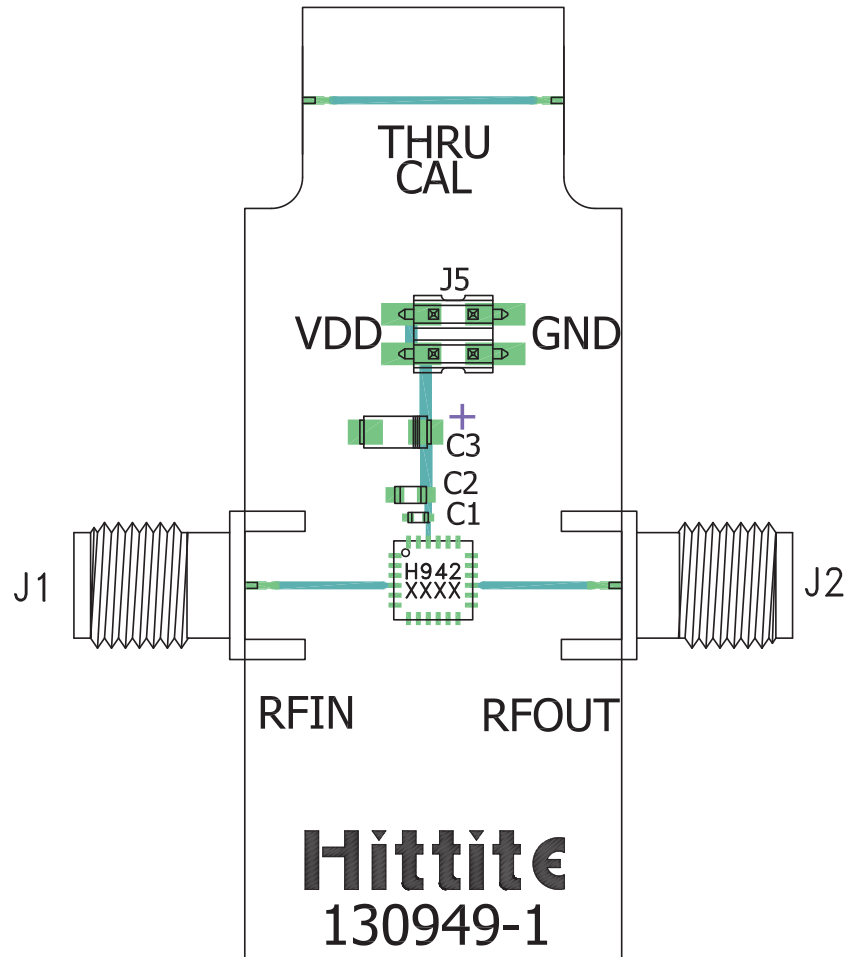
Application Circuit

Component	Value
C1	100 pF
C2	1,000 pF
C3	4.7 µF



**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 25 - 31 GHz OUTPUT**

Evaluation PCB



List of Materials for Evaluation PCB 130602 ^[1]

Item	Description
J1 - J2	PCB Mount SRI K Connector
J5	DC Pin
C1	100 pF Capacitor, 0402 Pkg.
C2	1,000 pF Capacitor, 0603 Pkg.
C3	4.7 μ F Tantalum Capacitor
U1	HMC942LP4E x2 Active Multiplier
PCB [2]	130949 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.